NSN 5961-01-069-7208

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No Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-069-7208 **Inclosure Material:** Metal **Overall Length:** Between 0.250 inches and 0.450 inches Overall Diameter: 0.875 inches **End Application:** Forrestal class cv **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-base, emitter open and 20.0 breakdown voltage, collector-to-emitter, base open and 20.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 60.00 amperes source cutoff current **Power Rating Per Characteristic:** 170.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 uninsulated wire lead **Specification Data:** 80131-release5584 professional/industrial association specification Shelf Life: N/a **Unit Of Measure: Demilitarization:**